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TPR 175

175 Watts, 50 Volts, Pulsed Avionics 1030 - 1090 MHz

GENERAL DESCRIPTION

The TPR 175 is a high power COMMON BASE bipolar transistor. It is designed for pulsed systems in the frequency band 1030-1090 MHz. The device has gold thin-film metallization for proven highest MTTF. The transistor includes input prematch for broadband capability. Low thermal resistance package reduces junction temperature, extends life.

CASE OUTLINE 55CX, STYLE 1

ABSOLUTE MAXIMUM RATINGS

Maximum Power Dissipation @ 25°C²

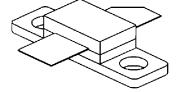
388 Watts

Maximum Voltage and Current

BVcesCollector to Base Voltage55 VoltsBVeboEmitter to Base Voltage3.5 VoltsIcCollector Current12.5 Amps

Maximum Temperatures

Storage Temperature - 65 to + 150°C
Operating Junction Temperature + 200°C



ELECTRICAL CHARACTERISTICS @ 25 °C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Pout Pin Pg η _c VSWR	Power Out Power Input Power Gain Collector Efficiency Load Mismatch Tolerance	F = 1090 MHz Vcc = 50 Volts PW = 10 µsec DF = 1% F = 1090 MHz	175 8.0	9.0 40	25	Watts Watts dB %

	3.5 55 10	0.45	Volts Volts °C/W
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Note 1: At rated output power and pulse conditions

2: At rated pulse conditions

NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

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